

/ Descriptions

SOT-89

NPN

Silicon NPN transistor in a SOT-89 Plastic Package.

/ Features

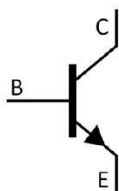
2SB649TA

Complementary pair with 2SB649TA.

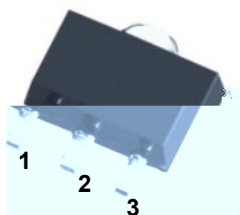
/ Applications

Low frequency power amplifier.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ Marking

h_{FE} Classifications Symbol	B	C	D
h_{FE} Range	60~120	100~200	160~320
Marking	H669B*	H669C*	H669D*

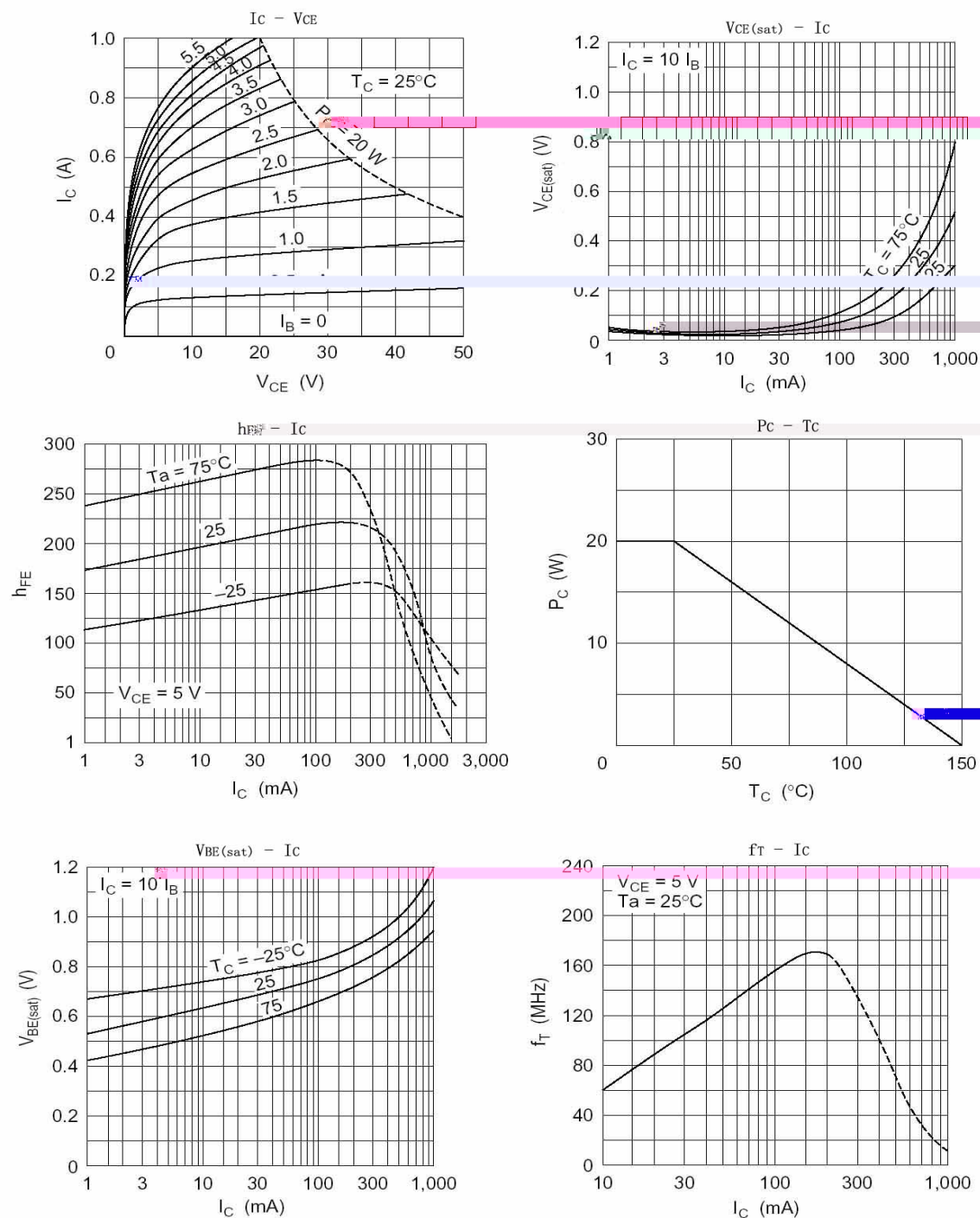
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	180	V
Collector to Emitter Voltage	V_{CEO}	160	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current-Continuous	I_C	1.5	A
Collector Current-Continuous (Pluse)	I_{CP}	3.0	A
Collector Power Dissipation	P_C	500	mW
Collector Power Dissipation	$P_C(T_c=25^{\circ}C)$	20	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C=1.0mA$ $I_E=0$	180			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=10mA$ $R_{BE}=\infty$	160			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E=1.0mA$ $I_C=0$	5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=160V$ $I_E=0$			10	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=5.0V$ $I_C=150mA$	60		320	
	$h_{FE(2)}$	$V_{CE}=5.0V$ $I_C=500mA$	30			
Base to Emitter Voltage	V_{BE}	$V_{CE}=5.0V$ $I_C=150mA$			1.5	V
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=500mA$ $I_B=50mA$			1.0	V
Transition Frequency	f_T	$V_{CE}=5.0V$ $I_C=150mA$		140		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$ $I_E=0$		14		pF

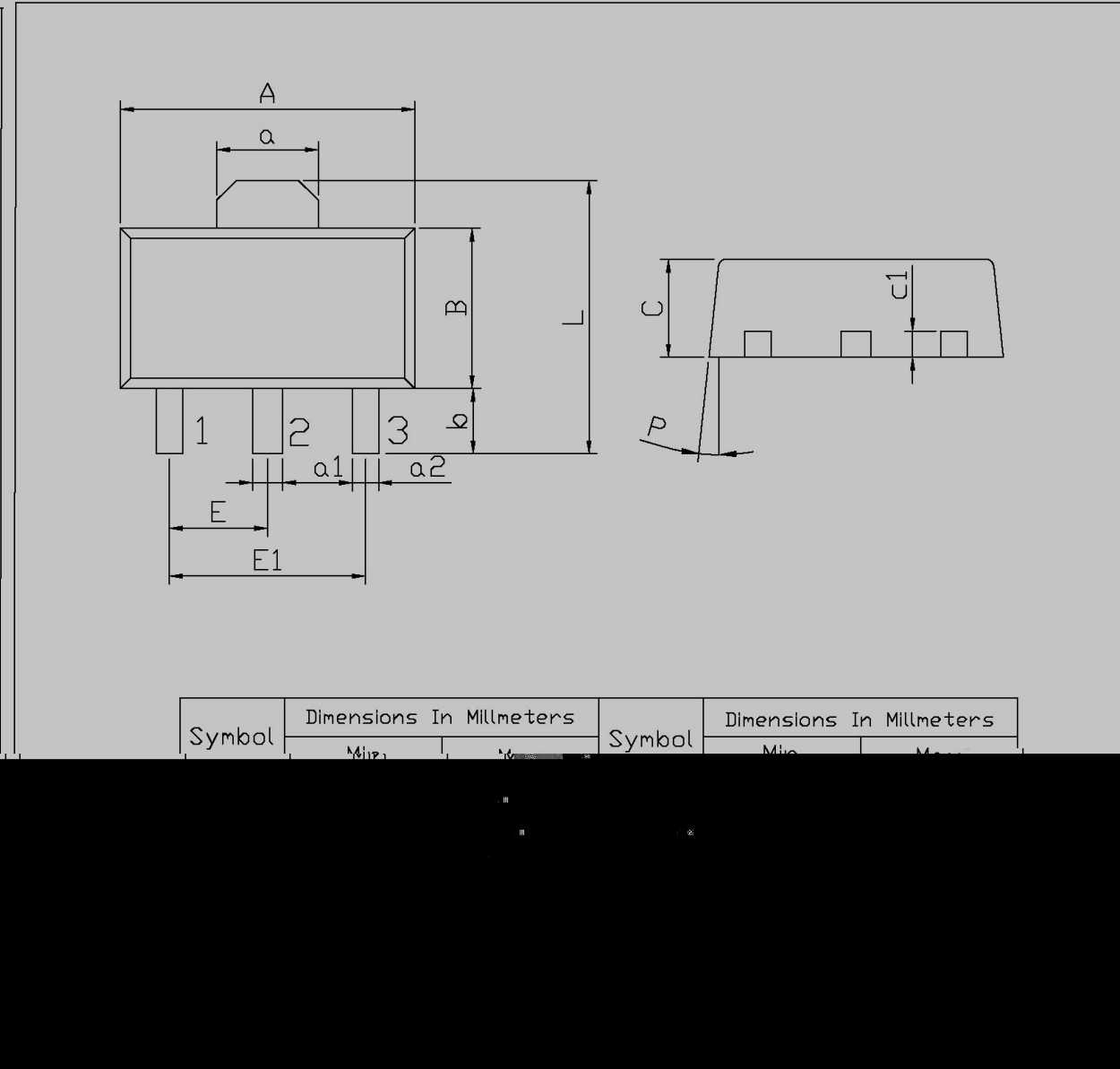
/ **Electrical Characteristic Curve**



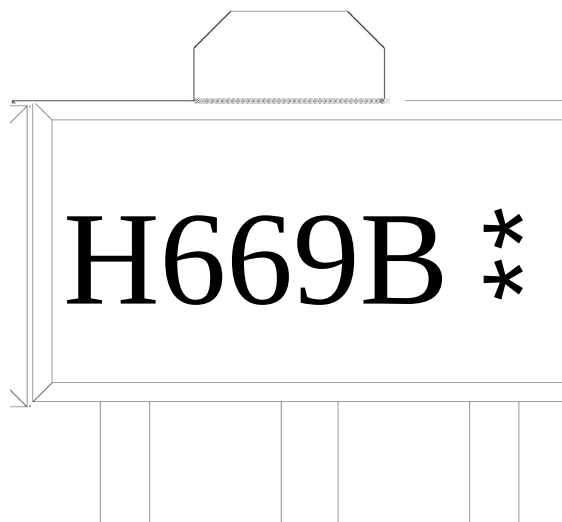
/ Package Dimensions

SOT-89

单位: mm



/ Marking Instructions



H

669

B

h_{FE}

**

Note:

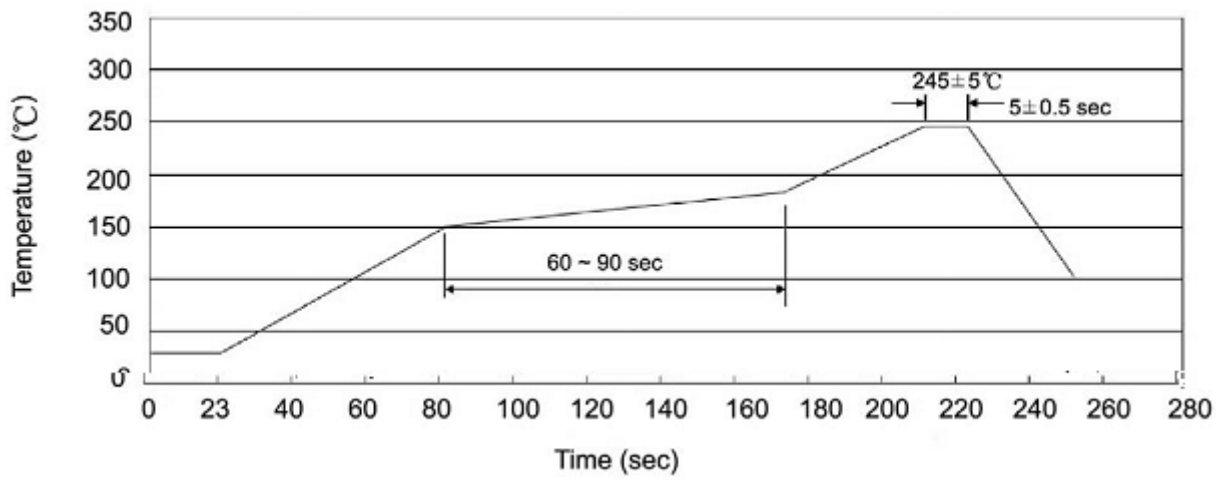
H: Company Code.

669: Product Type.

B h_{FE} Classifications Symbol

**: Lot No. Code, code change with Lot No.

() /



Note:

- | | | | | | |
|---|-------|-----|----|-----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | | 5±0.5sec; | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱
						"		

/ Notices